

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	267	(nanowire nanotube nano\$8) with oxide same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 06:51
L3	66	(nanowire nanotube nano\$8) with oxide same quantum same substrate	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 09:07
L4	3233	(nanowire nanotube nano\$8) with oxide same substrate	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 09:07
L5	1687	(nanowire nanotube nano\$8) with oxide with substrate	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 09:07
L6	527	(nanowire nanotube nano\$8) with oxide with (silicon semiconductor) near3 substrate	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 09:08
L7	80	(nanowire nanotube nano\$8) with oxide with (silicon semiconductor) near3 substrate and quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 10:22
L8	1	"6231744".PN.	USPAT; USOCR	OR	ON	2006/02/08 09:49
L9	1	"6139713".PN.	USPAT; USOCR	OR	ON	2006/02/08 09:49
L10	1	"4889631".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:02
L11	1	"5975976".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:03
L12	1	"5866975".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:04
L13	1	"5811917".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:05
L14	1	"5595638".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:05
L15	1	"5259957".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:05

L16	1	"5089092".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:06
L17	1	"4737799".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:06
L18	1	"6139713".PN.	USPAT; USOCR	OR	ON	2006/02/08 10:07
L19	2	09/276667	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 10:24
L20	2	09/867611	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 10:24
S49	1	10/810779	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:28
S50	3250	(insulat\$3 dielectric oxide) with (high near4 constant) same (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:45
S51	1278	S50 and (insulat\$3 dielectric oxide) with (high near4 constant) same (substrate)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:31
S52	255	S51 and (nanometer 'nm' angstrom micrometer) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:40
S53	19	S51 and (dot quantum quantum near3 dot anti adj dot) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:47
S54	33	S51 and (dot quantum quantum near3 dot anti adj dot island) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:50
S55	38	S51 and (dot quantum quantum near3 dot anti adj dot island cluster) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:44

S56	197	S51 and (nano\$7)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:44
S58	24	S51 and (nano-\$10)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 15:52
S59	197	S58 or S56	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 16:02
S61	1007	(insulat\$3 dielectric oxide) with (high near4 constant) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:28
S62	1	S61 and (nano-\$10) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:29
S63	5	S61 and (quantum) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:38
S64	143	S61 and (nanometer nm ansgtrom "u.m") with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:39
S65	0	S61 and ("u.m") with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:39
S66	143	S61 and (nanometer nm ansgtrom) with (trench opening groove hole via recess)	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:39
S67	5	(insulat\$3 dielectric oxide) with (high near4 constant) same (trench opening groove hole via recess) same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/02 17:48
S68	0	10/606670	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 09:46

S69	656	nano\$6 with aluminium adj oxide	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 09:47
S70	2	nano\$6 with aluminium adj oxide with quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 09:48
S71	8	(nanowire nanotube) with aluminium adj oxide same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2006/02/08 06:50
S72	1	"20010028872".PN.	US-PGPU B	OR	ON	2005/11/03 09:50
S73	1	"20010019565".PN.	US-PGPU B	OR	ON	2005/11/03 09:51
S74	1	"6359288".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:52
S75	1	"6231744".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:52
S76	1	"5747180".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:52
S77	1	"5581091".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:52
S78	1	"5581091".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:53
S79	1	"5330612".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:53
S80	1	"5330612".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:54
S81	1	"5202290".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:54
S82	1	"3945893".PN.	USPAT; USOCR	OR	ON	2005/11/03 09:54
S83	1	"5264722".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:20
S84	1	"6034468".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:21
S85	1	"6139626".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:21
S86	1	"5747180".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:23

S87	0	(nanowire nanotube) with titanium adj oxide same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 10:24
S88	0	(nanowire nanotube) with pentoxide same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 10:24
S89	0	(nanowire nanotube) with (tantalum near3 pentoxide) same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 10:25
S90	0	(nanowire nanotube) with (tantalum near3 toxide) same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 10:25
S91	0	(nanowire nanotube) with (tantalum near3 oxide) same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 10:25
S92	29	(nanowire nanotube) with (oxide) same quantum	US-PGPU B; USPAT; EPO; JPO	OR	ON	2005/11/03 10:25
S93	1	"5581091".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:28
S94	1	"5330612".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:29
S95	1	"5264722".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:29
S96	1	"5202290".PN.	USPAT; USOCR	OR	ON	2005/11/03 10:30